# **STEALTH**<sup>™</sup> Diode

18 A, 1200 V

# ISL9R18120G2, ISL9R18120S3S

#### Description

The ISL9R18120G2, ISL9R18120S3S is a STEALTH diode optimized for low loss performance in high frequency hard switched applications. The STEALTH family exhibits low reverse recovery current ( $I_{RR}$ ) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low  $I_{RR}$  and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

#### Features

- Stealth Recovery  $t_{rr} = 300 \text{ ns} (@ I_F = 18 \text{ A})$
- Max Forward Voltage,  $V_F = 3.3 \text{ V} (@ T_C = 25^{\circ}\text{C})$
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- These Devices are Pb-Free and are RoHS Compliant

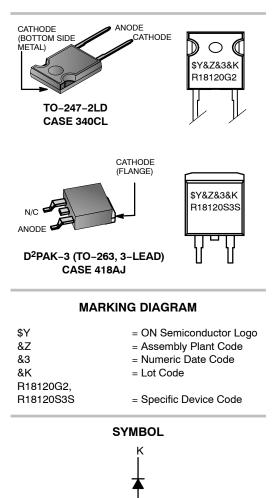
#### Applications

- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode



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#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### **DEVICE MAXIMUM RATINGS** (T<sub>C</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	1200	V	
Working Peak Reverse Voltage	V <sub>RWM</sub>	1200	V	
DC Blocking Voltage	V <sub>R</sub>	1200	V	
Average Rectified Forward Current (T <sub>C</sub> = 92°C)	I <sub>F(AV)</sub>	18	А	
Repetitive Peak Surge Current (20 kHz Square Wave)	I <sub>FRM</sub>	36	А	
Non-repetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	I <sub>FSM</sub>	200	А	
Power Dissipation	PD	125	W	
Avalanche Energy (1 A, 40 mH)	E <sub>AVL</sub>	20	mJ	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C	
Maximum Temperature for Soldering Leads at 0.063 in (1.6 mm) from Case for 10 s Package Body for 10 s	T <sub>L</sub> T <sub>PKG</sub>	300 260	°C °C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Packing Method	Tape Width	Quantity
ISL9R18120G2	R18120G2	TO-247-2LD	Tube	N/A	30
ISL9R18120S3ST	R18120S3S	TO-263-3LD (D <sup>2</sup> -PAK)	Reel	24 mm	800

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit
Thermal Resistance Junction to Case	$R_{\theta JC}$	TO-247, TO-263	-	-	1.0	°C/W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	TO-247	-	-	30	°C/W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	TO-263	-	-	62	°C/W

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
Off State Characteristics		-			•	•	
Instantaneous Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 1200 V	$T_C = 25^{\circ}C$	-	-	100	μA
			T <sub>C</sub> = 125°C	-	-	1.0	mA
On State Characteristics							
Instantaneous Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 18 A	T <sub>C</sub> = 25°C	-	2.7	3.3	V
			T <sub>C</sub> = 125°C	-	2.5	3.1	V
Dynamic Characteristics		-					
Junction Capacitance	CJ	$V_{R} = 10 \text{ V}, \text{ I}_{F} = 0 \text{ A}$		-	69	-	pF
Switching Characteristics							
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 100 A/µs, V <sub>R</sub> = 30 V		-	38	45	ns
		I <sub>F</sub> = 18 A, dI <sub>F</sub> /dt = 100 A/µs, V <sub>R</sub> = 30 V		-	60	70	ns
Reverse Recovery Time	t <sub>rr</sub>	$      I_F = 18 \text{ A}, \\       dI_F/dt = 200 \text{ A}/\mu\text{s}, \\       V_R = 780 \text{ V}, \\       T_C = 25^\circ\text{C} $		-	300	-	ns
Reverse Recovery Current	I <sub>rr</sub>			-	6.5	-	Α
Reverse Recovered Charge	Q <sub>rr</sub>			-	950	-	nC
Reverse Recovery Time	t <sub>rr</sub>	$    I_F = 18 \text{ A}, \\     dI_F/dt = 200 \text{ A}/\mu\text{s}, \\     V_R = 780 \text{ V}, \\     T_C = 125^\circ\text{C} $		-	400	-	ns
Softness Factor (t <sub>b</sub> / <sub>ta</sub> )	S			-	7.0	-	-
Reverse Recovery Current	I <sub>rr</sub>			-	8.0	-	А
Reverse Recovered Charge	Q <sub>rr</sub>			-	2.0	-	μC
Reverse Recovery Time	t <sub>rr</sub>			-	235	-	ns
Softness Factor (t <sub>b</sub> / <sub>ta</sub> )	S			-	5.2	-	-
Reverse Recovery Current	I <sub>rr</sub>			-	22	-	Α
Reverse Recovered Charge	Q <sub>rr</sub>			-	2.1	-	μC
Maximum di/dt During t <sub>b</sub>	dl <sub>M/</sub> dt			_	370	-	A/μs

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **TYPICAL PERFORMANCE CURVES**

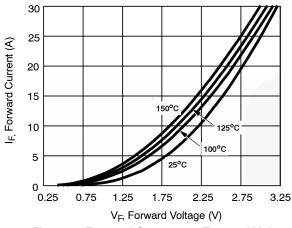
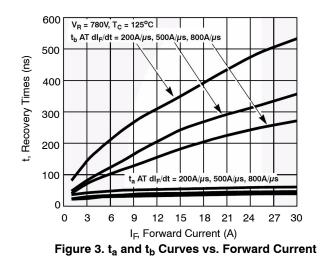


Figure 1. Forward Current vs. Forward Voltage



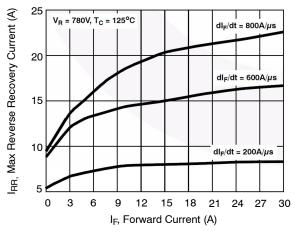
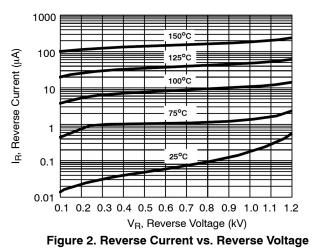


Figure 5. Maximum Reverse Recovery Current vs. Forward Current



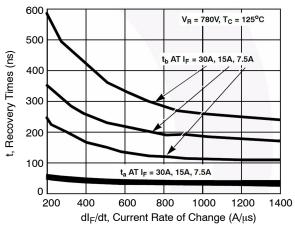
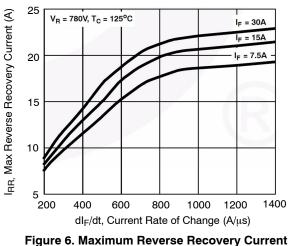
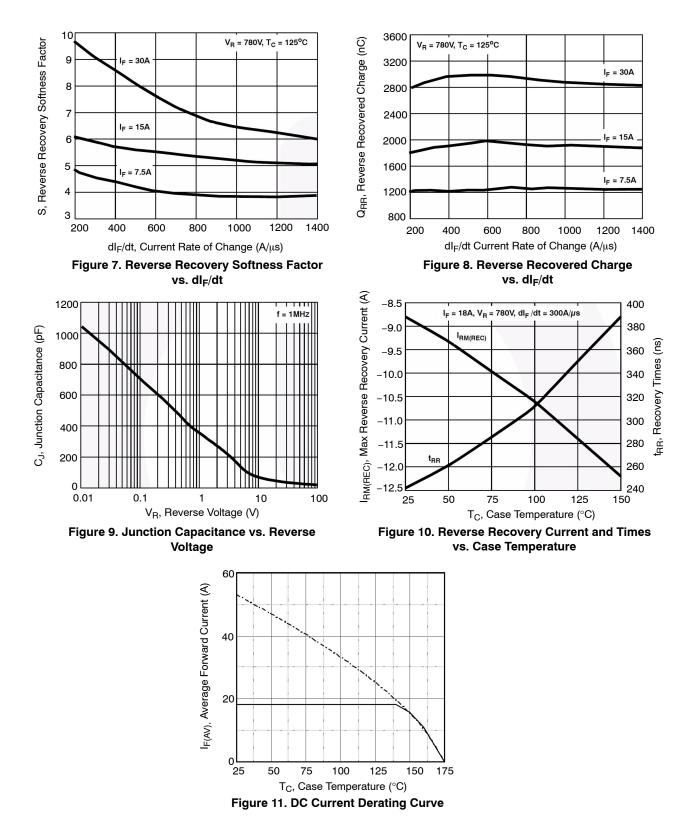


Figure 4.  $t_a$  and  $t_b$  Curves vs.  $dI_F/dt$ 

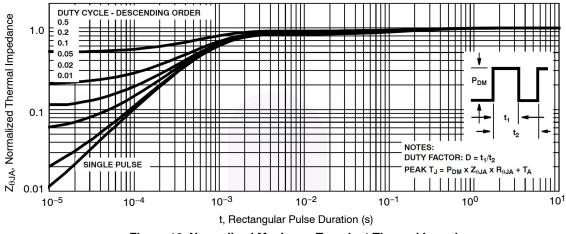


vs. dl<sub>F</sub>/dt

#### TYPICAL PERFORMANCE CURVES (continued)

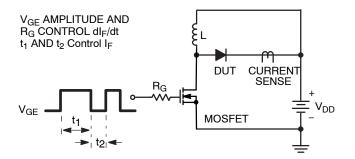


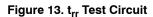
TYPICAL PERFORMANCE CURVES (continued)





#### **TEST CIRCUIT AND WAVEFORMS**





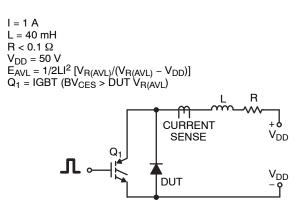


Figure 15. Avalanche Energy Test Circuit

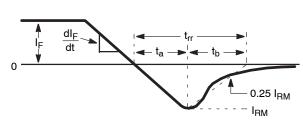


Figure 14. t<sub>rr</sub> Waveforms and Definitions

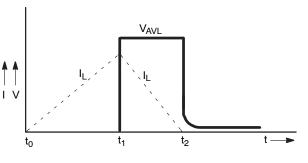


Figure 16. Avalanche Current and Voltage Waveforms

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**MILLIMETERS** 

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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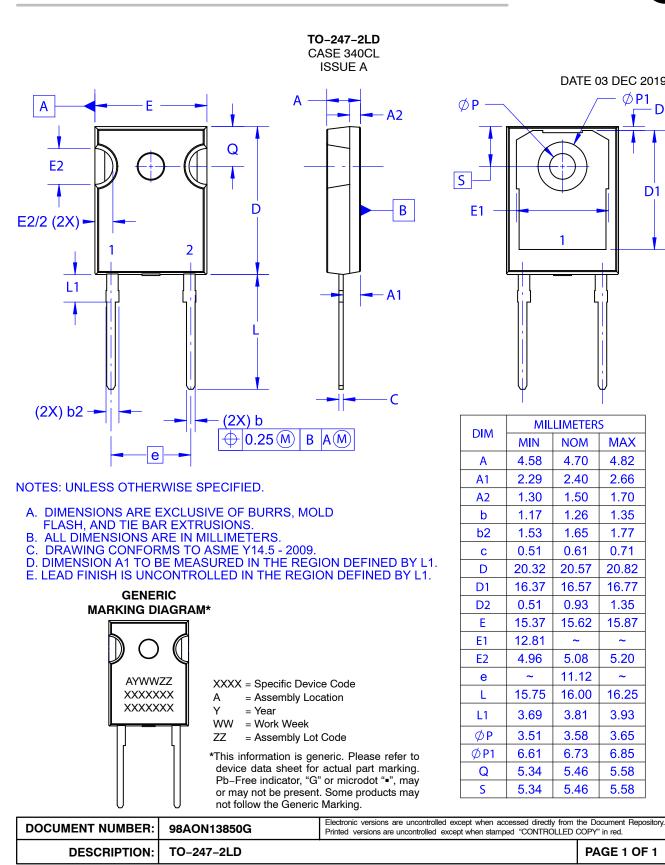
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ØP1



D2

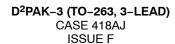
D1



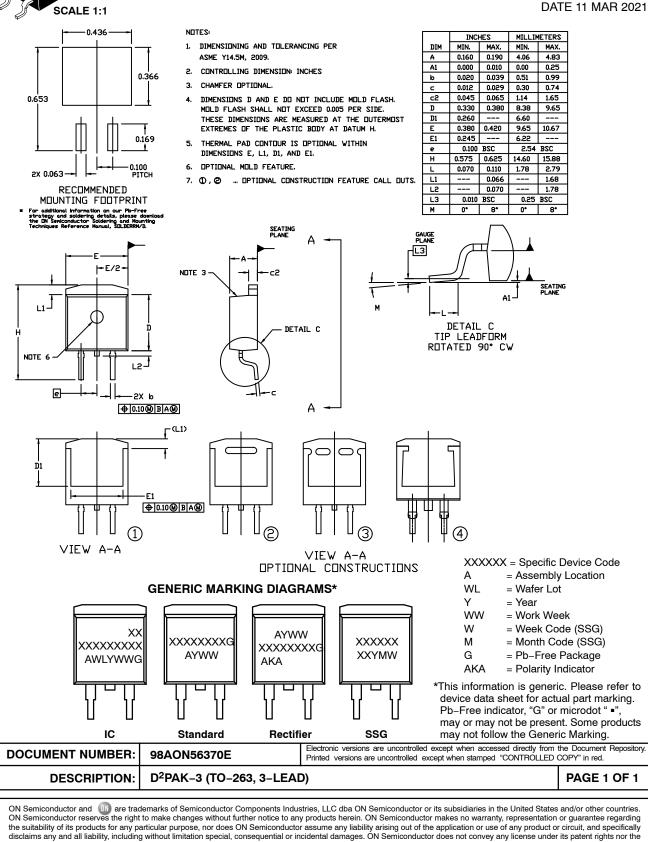
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#### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS









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